

## Micro Embedded Infrared Receiver Module

0-05-07-23 Preliminary

Module No.: PIC-8002ASE

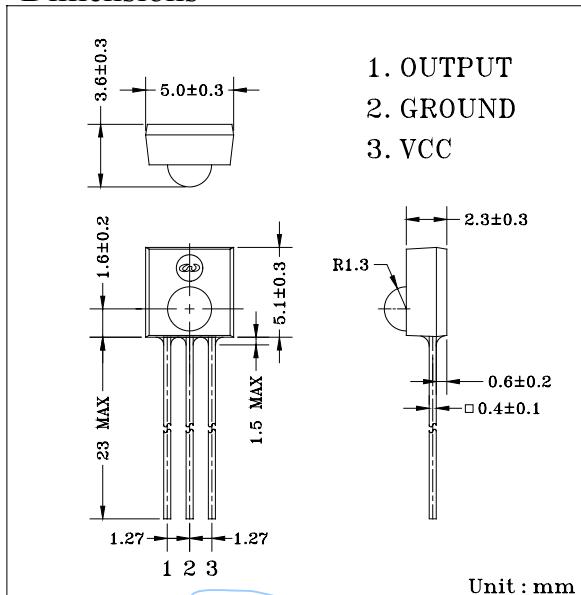
### 1. Features:

- Microminiature size
- Embedded protection
- Built-in exclusive IC
- Wide half angle & long reception distance
- Continuous Signal Acceptable
- Suitable for R-C oscillating transmitter
- High protection ability to EMI
- Side view
- Wide voltage operating: 2.7V ~ 5.5V

### 2. Applications

- AV instruments (Audio, TV, VCR, CD player)
- Home appliances (Air-conditioner, Fan, Light.)
- Remote control for wireless devices

### Dimensions



### 3. Absolute Maximum Ratings

| Parameter                | Symbol | Ratings   | Unit |
|--------------------------|--------|-----------|------|
| Supply Voltage           | Vcc    | 6.0       | V    |
| Operating Temperature    | Topr   | -10 ~ +60 | °C   |
| Storage Temperature      | Tstg   | -20 ~ +75 | °C   |
| Soldering Temperature *1 | Tsol   | 240       | °C   |

\*1 At the position of 2mm from the bottom of the package within 5 seconds.

(Ta=25°C)

### 4. Electro-optical Characteristics

(Ta=25°C)

| Parameter                 | Symbol | Conditions         | Min.               | Typ. | Max. | Unit |
|---------------------------|--------|--------------------|--------------------|------|------|------|
| Supply Voltage            | Vcc    |                    | 2.7                |      | 5.5  | V    |
| Current Consumption       | Icc    | Input Signal = 0   |                    | 1.0  | 1.2  | mA   |
| Reception Distance        | d      | 200±5Lux, Vcc=3.0V | 7                  | 10   |      | m    |
| Half Angle                | Δθh    |                    |                    | ±45  |      | deg  |
| B.P.F. Center Frequency   | Fo     |                    |                    | 37.9 |      | kHz  |
| Peak Wavelength           | λp     |                    |                    | 940  |      | nm   |
| Signal Output             | So     |                    | --- Active Low --- |      |      |      |
| High Level Output Voltage | Voh    |                    | Vcc-0.5            |      |      | V    |
| Low Level Output Voltage  | Vol    |                    |                    | 0.2  | 0.4  | V    |
| High Level Pulse Width    | Twh    | Burst Wave = 600μs | 500                | 600  | 700  | μs   |
| Low Level Pulse Width     | Twl    |                    | 500                | 600  | 700  | μs   |

### 5. Reliability Test Items

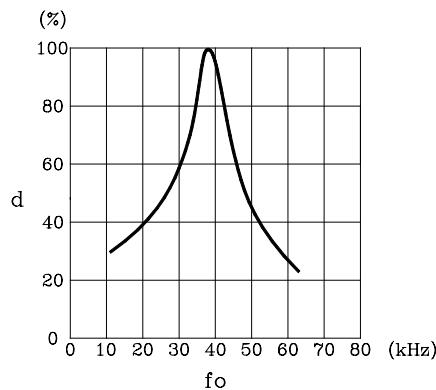
(Ta=25°C)

| Test Items                          | Test Conditions               | Ratings   |
|-------------------------------------|-------------------------------|-----------|
| High Temperature Storage            | Ta=60°C, Vcc=3.0V             | t=240hr.  |
| Low Temperature Storage             | Ta=-10°C, Vcc=3.0V            | t=240hr.  |
| High Temperature High Humid Storage | Ta=40°C, 90%RH, Vcc=3.0V      | t=240hr.  |
| Temperature Cycling                 | -20°C (30min) ~ +70°C (30min) | 20 cycles |
| Soldering Heat                      | 240±5°C                       | 5 sec.    |

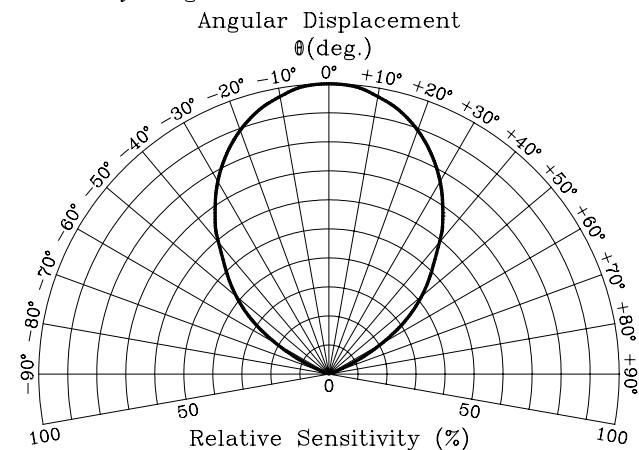
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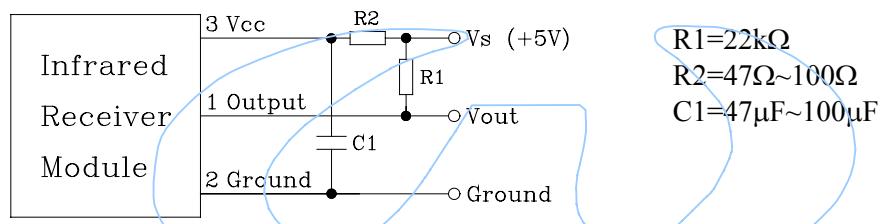
Relative Reception Distance vs  
Transmitter Carrier Frequency



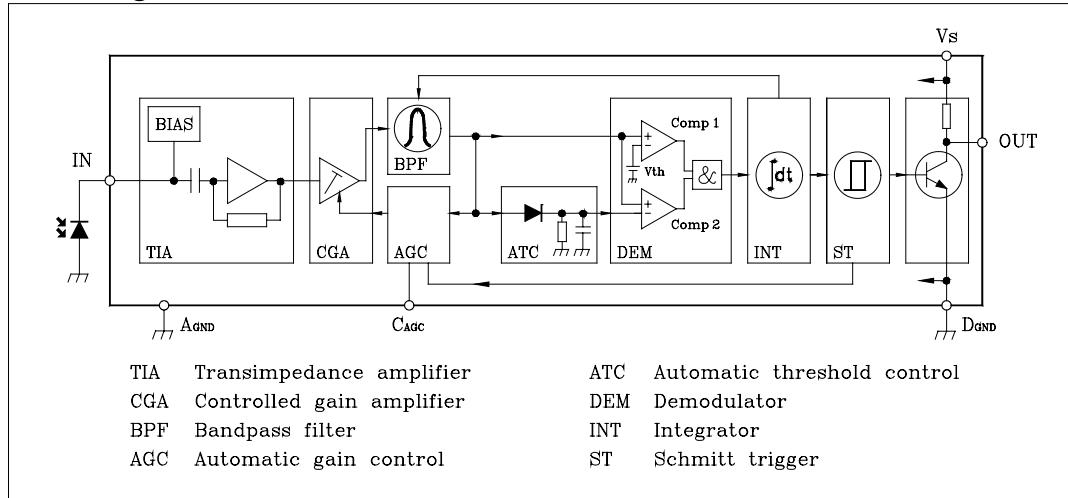
Sensitivity Diagram



In case of noisy power supply, please serially insert  $100\Omega$  resistor and about  $47\mu F$  electrolytic capacitor in Vcc line and ground as follows:-



Block Diagram



### Standard Inspection

Among electrical characteristics, total quantity will be inspected as below:-

- ◎ Distance between emitter and detector
- ◎ Current consumption
- ◎ H level output voltage
- ◎ L level output voltage

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### Testing Method

Distance between emitter and detector specifies maximum distance that output waveform satisfies the standard (FIG-3) under the conditions below against the standard transmitter.

#### a. Measuring place

Indoor without extreme reflection of light.

#### b. Ambient light source

Detecting surface illumination is  $200 \pm 5$ Lux under ordinary white fluorescence lamp of no high frequency lightning.

#### c. Standard transmitter

Transmitter wave indicated in FIG-2 of standard transmitter is arranged to satisfy  $V_o \geq 50mV_{p-p}$  under the measuring circuit specified in FIG-3

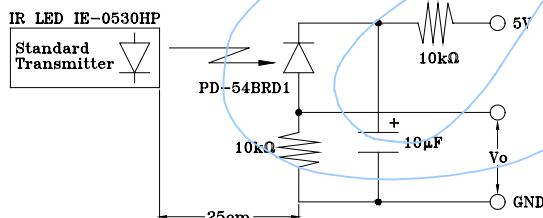


FIG-3 Power Output Measurement Circuit

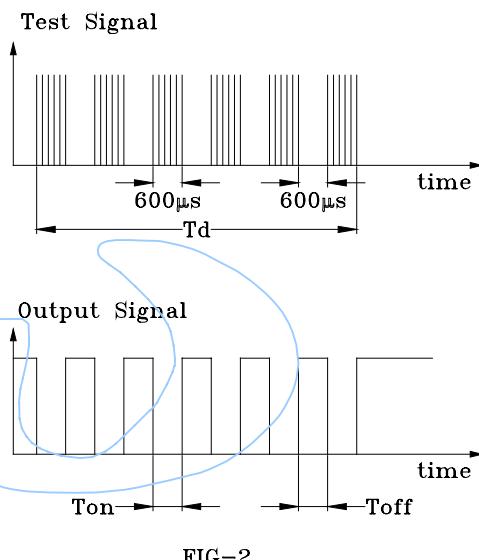
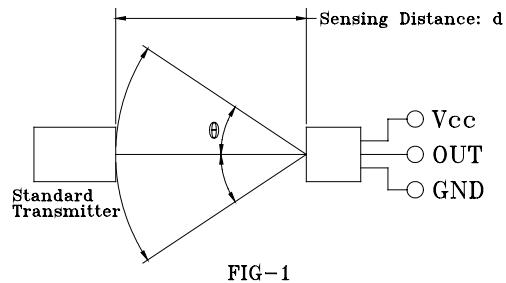
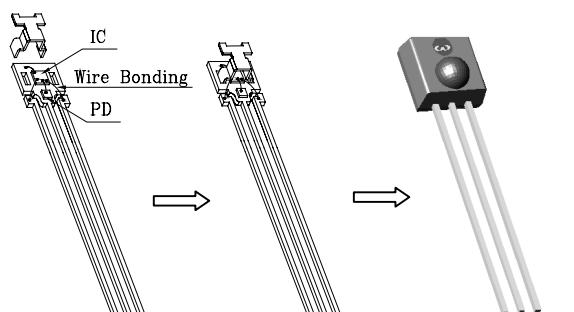


FIG-2

### Embedded Design

This design (Fig-4) is to install a metal case on the carrier lead frame to cover the semiconductor components, in order to shield it electromagnetically within the epoxy resin encapsulation.



Die Bonding      Embedded Cover      After  
                        Protection          Encapsulation

FIG-4 Embedded Design

### Precautions for Use

- Store and use where there is no force causing transformation or change in quality.
- Store and use where there is no corrosive gas or sea (salt) breeze.
- Store and use where there is no extreme humidity.
- Solder the lead pin within the condition of ratings. After soldering, do not add exterior force.
- Do not wash this device. Wipe the stains of diode side with a soft cloth. You can use the solvent, ethyl alcohol, or methyl alcohol only.
- To prevent static electricity damage to the pre-amp, make sure that the human body, the soldering iron are connected to ground before using.